### TEXAS INSTRUMENTS Data sheet acquired from Harris Semiconductor

SCHS026C – Revised September 2003

# CMOS Quad Bilateral Switch

For Transmission or Multiplexing of Analog or Digital Signals

High-Voltage Types (20-Volt Rating)

■ CD4016B Series types are quad bilateral switches intended for the transmission or multiplexing of analog or digital signals. Each of the four independent bilateral switches has a single control signal input which simultaneously biases both the p and n device in a given switch on or off.

The CD4016 "B" Series types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

#### Features:

- 20-V digital or ± 10-V peak-to-peak switching
- 280-Ω typical on-state resistance for 15-V operation
- Switch on-state resistance matched to within 10  $\Omega$  typ. over 15-V signal-input range
- High on/off output-voltage ratio:
  65 dB typ. @ f<sub>is</sub> = 10 kHz, R<sub>L</sub> = 10 kΩ
- High degree of linearity: <0.5% distortion typ. @ f<sub>is</sub> = 1 kHz, V<sub>is</sub> = 5 V<sub>p-p</sub>, V<sub>DD</sub>-V<sub>SS</sub> ≥ 10 V, R<sub>L</sub> = 10 kΩ
- Extremely low off-state switch leakage resulting in very low offset current and high effective off-state resistance:
   100 pA typ. @ VDD-VSS=18 V, TA=25°C
- Extremely high control input impedance (control circuit isolated from signal circuit:  $10^{12} \Omega$  typ.
- Low crosstalk between switches:
  -50 dB typ. @ fis = 0.9 MHz, RL = 1 kΩ
- Matched control-input to signal-output capacitance:
- Reduces output signal transients Frequency response, switch on = 40 MHz

(typ.)

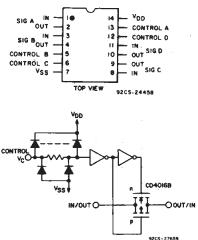
- 100% tested for quiescent current at 20 V
  Maximum control input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V at 25°C
- 5-V, 10-V, and 15-V parametric ratings Applications:
- Analog signal switching/multiplexing

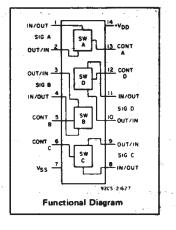
Signal gating	Modulator
Squeich control	Demodulator
Chopper	Commutating switch

- Digital signal switching/multiplexing
- CMOS logic implementation
- Analog-to-digital & digital-toanalog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain









Schematic diagram - 1 of 4 identical sections.

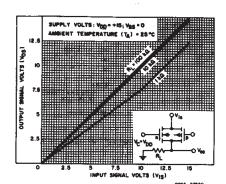
#### **RECOMMENDED OPERATING CONDITIONS**

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following range:

CHARACTERISTIC	LIN	UNITS	
	Min.	Max.	UNITS
Supply Voltage Range (For T <sub>A</sub> = Full Package Temperature Range)	3	18	• • • •

#### MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to V <sub>SS</sub> Terminal)	-0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	-0.5V to V <sub>DD</sub> +0.5V
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (PD):	
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$	
For T <sub>A</sub> = +100°C to +125°C	Derate Linearity at 12mW/ <sup>Q</sup> C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR T <sub>A</sub> = FULL PACKAGE-TEMPERATURE RANGE	
OPERATING-TEMPERATURE RANGE (TA)	
STORAGE TEMPERATURE RANGE (Tstg)	
LEAD TEMPERATURE (DURING SOLDERING):	



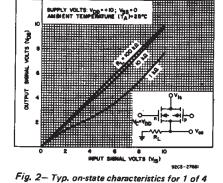


Fig. 1- Typ. on-state characteristics for 1 of 4 switches with  $V_{DD}$  = +15 V,  $V_{SS}$  = 0 V.

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switches with V<sub>DD</sub>=+10 V, V<sub>SS</sub>=0 V.

#### ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TE TE	est conditi	IONS						CATED 3 (°C)	I	U N I T
			VIN	V <sub>DD</sub>					-	25	S
	Station and		(V) 0.5	(V) 5	- <b>55</b>	<b>40</b>	+85		Typ.		
Quiescent Device			0,10	10	0.25		15		0.01 0.01	0.25	1
Current, IDD			0,15	15	1	1	30		0.01	0.5	μΑ
			0,20	20	5	<u> </u>	150	1	0.02	5	
Signal Inputs (V <sub>is</sub>	) and Output	(V <sub>os</sub> )			<u>_</u>	Ţ		1.00	10.02	<u> </u>	
On-State Resistance, r <sub>on</sub>		V <sub>is</sub> =V <sub>DD</sub> o	r V <sub>SS</sub>	10	600	610	840	960		660	
Max.	V <sub>C</sub> = V <sub>DD</sub> R <sub>L</sub> = 10kΩ Returned	V <sub>is</sub> =4.75 to	5.75 V	10	1870	1900	2380	2600	-	2000	
	to V <sub>DD</sub> -V <sub>SS</sub>	V <sub>is</sub> =V <sub>DD</sub> ₀ı	r V <sub>SS</sub>	15	360	370	520	600	_	400	Ω
	2	V <sub>is</sub> =7.25 to	7.75 V	15	775	790	1080	1230	-	850	
∆On-State Resistance	·			5	_		-	_	15	-	
Between Any	$R_{L}$ =10 k $\Omega$ ,	$V_{C} = V_{DD}$		10	_	-	-		10	-	Ω
2 Switches, ∆r <sub>on</sub>				15	-	-	-	-	5		
Total Harmonic Distortion, THD	VC=VDD = = 5V (Sine w RL=10 kΩ, 1	vave centere	-	_	_	-	0.4	-	%		
-3dB Cutoff Frequency (Switch on)	VC=VDD= Vis(p-p) =5 centered or	V (Sine way	/e		_	-	- ;	_	40	-	MHz
-50dB Feed- through Frequency (Switch off)	Vc=Vss= (Sine wave R <sub>L</sub> = 1 lkΩ	-5V, V <sub>is(p-1</sub> centered on	p)=5∨ 0∨)		-	-	-	_	1.25	_	MHz
Input/Output Leakage Current (Switch off) I <sub>is</sub> Max.	$V_{C} = 0 V$ $V_{is} = 18 V$ , $V_{is} = 0 V$ , $V_{os} = 18 V$			18	±0.1	±0.1	±1	±1	104	±0.1	μΑ
–50 dB Crosstalk Frequency	$V_{C}(A) = V_{D}$ $V_{C}(B) = V_{S}$ $V_{is}(A) = 5 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	ς = -5V, / <sub>p-p</sub> ,	3	-	-	-	_	0.9	-	MHz	
Propagation	RL = 200 ks			5	. <u> </u>	_	_	<u> </u>	40	100	
Delay (Signal	Vc = Vpp, cL = 50 pF	vss = GND	•	10	_	_	-	_	20	40	ns
Input to Signal Output) t <sub>pd</sub>	Vis = Square 0 to VDD t <sub>r</sub> , t <sub>f</sub> = 20 ns	Wave	15	-	-	-	-	15	30		
Capacitance: Input, C <sub>is</sub>	V <sub>DD</sub> = +5 V		- <u>-</u>		_	_	_	_	4	_	
Output, C <sub>os</sub>	$V_{C} = V_{SS} =$				-	-	-	-	4	-	pF
Feedthrough, C <sub>ios</sub>					_	_			0.2		

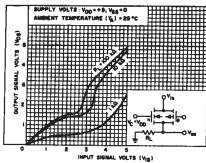


Fig. 3–Typ. on-state characteristics for 1 of 4 switches with  $V_{DD}$  = +5 V,  $V_{SS}$  = 0 V.

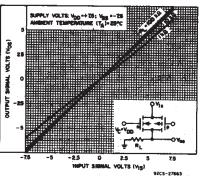


Fig. 4-Typ. on-state characteristics for 1 of 4 switches with V<sub>DD</sub>=+7.5 V, V<sub>SS</sub>=-7.5 V.

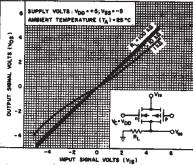
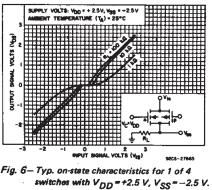


Fig. 5- Typ. on-state characteristics for 1 of 4 switches with  $V_{DD} = +5 V$ ,  $V_{SS} = -5 V$ .

92CS-27664



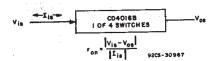
ELECTRICAL CHARACTERISTICS (cont'd)

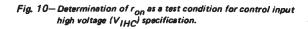
CHARACTERISTIC	TEST CONDITIONS		LIMITS AT INDICATED TEMPERATURES ( <sup>O</sup> C)						U N I T	
			55	-40			+2	1	s	
Control (V <sub>C</sub> )	· · · · · · · · · · · · · · · · · · ·	_ (v)		40	+85	+125	Тур.	Max.		
Control Input Low Voltage, VILC (Max.)	$  _{i_{s}}  < 10 \mu A$ $V_{i_{s}} = V_{SS}, V_{OS} = V_{DD}$ and $V_{i_{s}} = V_{DD}, V_{OS} = V_{SS}$	5,10, 15	0.9	0.9	0.4	0.4	<u> </u>	0.7	v.	Fig. 7- Typ. on-state characteristics as a function of temp. for 1 of 4 switches with $V_{DD} = +5 V$ , $V_{SS} = -5 V$ .
Control Input High Voltage, VIHC	See Fig. 10	5 10 15		•	7 (	(Min.) (Min.) (Min.)	<b></b>	L	v	
Input Current, IN (Max.)	$V_{is} \leq V_{DD}$ $V_{DD} - V_{SS} = 18 V$ $V_{CC} \leq V_{DD} - V_{SS}$	18	±0.1	±0.1	±1	±1	±10-5	±0.1	μA	30-LOAD CARACTTARCE (CL)-CPTUTURE * CARETER*2.3+2.5-40 pF CTUTURE AND MATER MULLEOUT 202 COMPATING AND AND COMPATING * CARETER*2.3+2.5-40 pF CTUTURE AND AND COMPATING * CARETER*2.3+2.5-40 pF COMPATING AND COMPATING * CARETER*2.3+
Crosstalk (Con- trol Input to Signal Output)	$V_C = 10 V (Sq. Wave)$ $t_r, t_f = 20 ns$ $R_L = 10 k\Omega$	10	-	-	_	_	50	-	mV°	
Turn-On Propagation Delay	t <sub>r</sub> , t <del>j</del> = 20 ns CL = 50 pF RL = 1 kΩ	5 10 15		-	- - -	-	35 20 15	70 40 30	ns	ост <sup>2</sup> 468 2 468
Maximum Control Input Repetition Rate	$\label{eq:statestar} \begin{array}{l} V_{is} = V_{DD}, V_{SS} = GND, \\ R_L = 1 \ k\Omega \ to \ gnd, \\ C_L = 50 \ pF, \\ V_C = 10 \ V(Square \\ wave \ centered \ on \ 5 \ V) \\ t_r, \ t_f = 20 \ ns, \\ V_{OS} = \frac{V}{2} \ V_{OS} \circledast 1 \ kHz \end{array}$	10				_	10	<del>-</del>	MHz	Off.
Input Capacitance, <sup>C</sup> IN			-	_	-	-	5	7.5	μF	3      300 <sup>2</sup> FRCTWRG AND METER NULLED OUT      38.5        3      300 <sup>2</sup> FRCTWRG AND METER NULLED OUT      38.5        3      300 <sup>2</sup> FRCTWRG AND METER NULLED OUT      39.7        3      200 <sup>2</sup> FRCTWRG AND METER NULLED OUT      37.7        3      200 <sup>2</sup> FRCTWRG AND METER NULLED OUT      37.7        3      200 <sup>2</sup> FRCTWRG AND METER NULLED OUT      37.7        3      200 <sup>2</sup> FRCTWRG AND

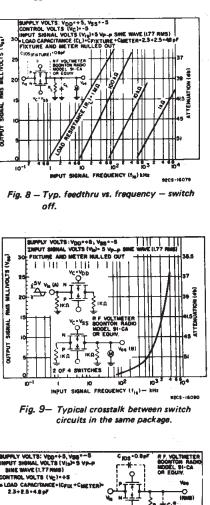
				Switch In	nput			Switch	Output
VDD	Vis		V <sub>os</sub> (V)						
(V)	(V)	–55°C	-40°C	25°C*	25°C▲	+85°C	+125°C	Min.	Max.
5	0	0.25	0.2	0.2	0.16	0.12	0.14	-	0.4
5	5	0.25	-0.2	-0.2	0.16	0.12	0.14	4.6	
10	0	0.62	0.5	0.5	0.4	0.3	0.35		0.5
10	10	-0.62	0.5	0.5	-0.4	-0.3	-0.35	9.5	
15	0	1.8	1.4	1.5	1.2	1	1.1	-	1.5
15	15	-1.8	-1.4	-1.5	-1.2	-1	-1.1	13.5	

\* Plastic package

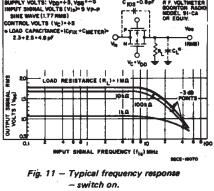
A Ceramic package





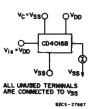


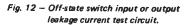
SUPPLY VOLTS: VDD\*+5V, VSS\*-5V

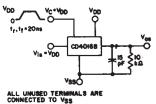


1. · · · ·	the second s	
TYPICAL ON-STATE RESISTANCI	E CHARACTERISTICS, $T_A = 3$	25 <sup>0</sup> C

CHARAC- TERISTIC*	SUPPLY CONDITION		د . مرکز	n si y A ses	LO	AD			
				1k52	RL	• 10kΩ	R <sub>L</sub> = 100kΩ		
	V <sub>DD</sub> (V)	V <sub>SS</sub> (V)	VALUE (52)	v V <sub>is</sub> (V).	VALUE {\2]	Vin (V)	VALUE (Ω)	V <sub>is</sub> (V)	
_	+15		200	+15	200	+15	180	+15	
ron	+15	0	200	0	200	0	200	0	
ron (max.)	+15	0	300	+11	300	+9.3	320	+9.2	
	+10	0	290	+10	250	+10	240	+10	
ron		0	290	0	250	0	300	0.	
r <sub>on</sub> (max.)	+10	0	500	+7.4	560	+5.6	610	+5.5	
	+ 5	0	860	+ 5	470	+ 5	450	+ 5	
r <mark>on </mark>	7 9		600	0	- 580	0	800	0	
r <sub>on</sub> (max.)	+ 5	0	1.7k	+4.2	7k	+2.9	3 <b>3</b> k	+2.7	
-	+7.5	-7.5	200	+7.5	200	+7.5	180	+7.5	
ron	+7.5	-7.5	200	~7.5	200	7.5	180	-7.5	
r <sub>on</sub> (max.)	+7.5	-7.5	290	±0.25	280	±25	400	±0.25	
	+ 5	- 5	260	+ 5	250	+ 5	240	+ 5	
ron	T D	- 5	310	- 5	250	- 5	- 240	- 5	
r <sub>on</sub> (max.)	+ 5	- 5	600	±0.25	580	±0.25	760	±0.25	
	+2.5	25	590	+2.5	450	+2.5	490	+2.5	
ron	72.5	-2.5	720	-2.5	520	-2.5	520	-2.5	
r <sub>on</sub> (max.)	+2.5	-2.5	232k	±0.25	300k	±0.25	870k	±0.25	

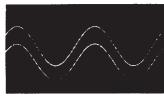






9205-27668 Fig. 13 - Test circuit for square-wave response.

\* Variation from aperfect switch,  $r_{on} = 0 \Omega$ .



9205-27612

Fig. 14 - Typical sine wave response of VDD =  $+7.5 V, V_{SS} = -7.5 V.$ 



SCALE: X = 100 ns/DIV Y = 5.0 V/DIV

9205-27615

Fig. 17 - Typical square wave response at  $V_{DD} = V_C = +15 V$ ,  $V_{SS} = Gnd$ .



9205-27613

- Fig. 15 Typical sine wave response of  $V_{DD}$  = +5 V,  $V_{SS}$  = -5 V.



SCALE: X = 100 ns/DIV Y = 5.0 V/DIV 92CS - 27616

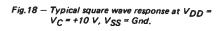






Fig. 19 - Typical square wave response at VDD = V<sub>C</sub> = +5 V, V<sub>SS</sub> = Gnd.



92CS - 27614

Fig. 16 – Typical sine wave response of  $V_{DD}$  = +2.5 V,  $V_{SS}$  = -2.5 V.

### CD4016B Types

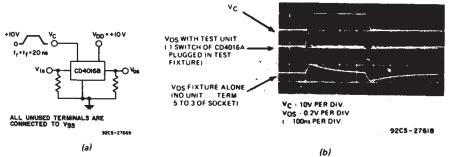
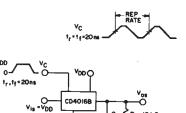


Fig.20 - Crosstalk-control input to signal output.



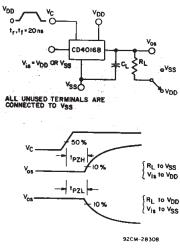
IO k.O

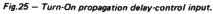


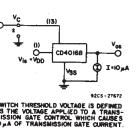
V<sub>DD</sub>

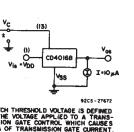
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Fig. 22 - Max. control-input repetition rate.









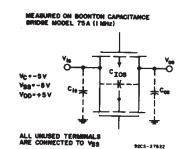


Fig.24 - Capacitance CIOS and COS.

+10V

0-

ty.14=20ms

Ľĉ

ALL UNUSED TERMINALS ARE CONNECTED TO VSS

CD40(68

vss⊘

Fig.21 - Propagation delay time signal input

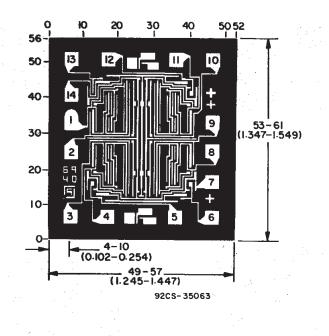
(VIS) to signal output (VOS).

200 K

92C5-27670R

Fig.23 - Switch threshold voltage.

Dimensions and pad layout for CD4016BH



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils  $(10^{-3} \text{ inch})$ .



4-Feb-2021

### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9064001CA	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9064001CA CD4016BF3A	Samples
CD4016BE	ACTIVE	PDIP	Ν	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4016BE	Samples
CD4016BEE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4016BE	Samples
CD4016BF	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4016BF	Samples
CD4016BF3A	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9064001CA CD4016BF3A	Samples
CD4016BM	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4016BM	Samples
CD4016BM96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4016BM	Samples
CD4016BMG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4016BM	Samples
CD4016BMT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4016BM	Samples
CD4016BNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4016B	Samples
CD4016BPW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM016B	Samples
CD4016BPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM016B	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.



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<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD4016B, CD4016B-MIL :

Catalog: CD4016B

Military: CD4016B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

## PACKAGE MATERIALS INFORMATION

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Texas Instruments

#### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4016BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4016BMT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4016BNSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4016BPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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## PACKAGE MATERIALS INFORMATION

17-Dec-2020



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4016BM96	SOIC	D	14	2500	853.0	449.0	35.0
CD4016BMT	SOIC	D	14	250	210.0	185.0	35.0
CD4016BNSR	SO	NS	14	2000	853.0	449.0	35.0
CD4016BPWR	TSSOP	PW	14	2000	367.0	367.0	35.0

### MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## **GENERIC PACKAGE VIEW**

# CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



# J0014A



## **PACKAGE OUTLINE**

### CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



NOTES:

- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
  Falls within MIL-STD-1835 and GDIP1-T14.



## J0014A

# **EXAMPLE BOARD LAYOUT**

### CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE





D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



### N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



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